

# CDBJFSC5650-G

**Reverse Voltage: 650 V**

**Forward Current: 5 A**

**RoHS Device**



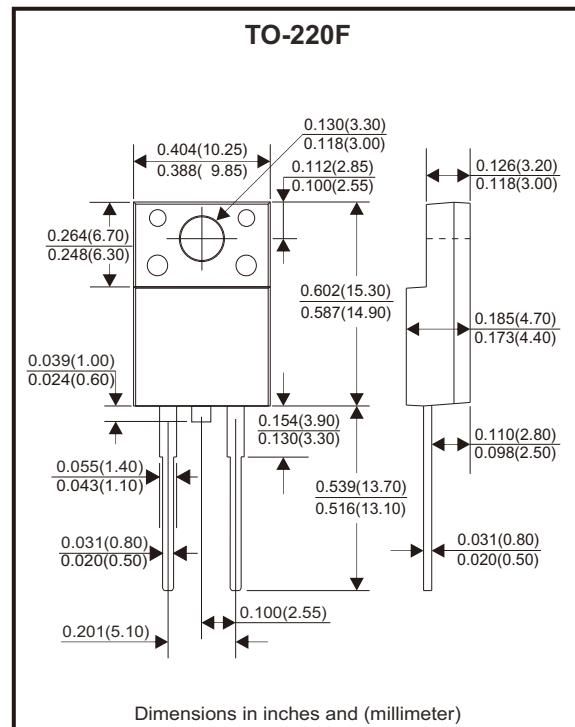
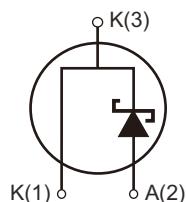
## Features

- Rated to 650V at 5 Amps.
- Short recovery time.
- High speed switching possible.
- High frequency operation.
- High temperature operation.
- Temperature independent switching behaviour.
- Positive temperature coefficient on VF.

## Mechanical data

- Case: TO-220F, molded plastic.

## Circuit Diagram



## Maximum Rating (at $T_A=25^\circ\text{C}$ unless otherwise noted)

Parameter	Conditions	Symbol	Value	Unit
Repetitive peak reverse voltage		$V_{RRM}$	650	V
Surge peak reverse voltage		$V_{RSM}$	650	V
DC blocking voltage		$V_{DC}$	650	V
Typical continuous forward current	$T_c = 150^\circ\text{C}$	$I_F$	5	A
Repetitive peak forward surge current	$T_c = 25^\circ\text{C}$ , $t_p = 10\text{ms}$ Half sine wave, $D = 0.3$	$I_{FRM}$	30	A
Non-repetitive peak forward surge current	$T_c = 25^\circ\text{C}$ , $t_p = 10\text{ms}$ Half sine wave	$I_{FSM}$	60	A
Power dissipation	$T_c = 25^\circ\text{C}$	$P_{TOT}$	30.9	W
	$T_c = 110^\circ\text{C}$		13.4	
Typical thermal resistance	Junction to case	$R_{\theta JC}$	4.85	$^\circ\text{C}/\text{W}$
Operating junction temperature range		$T_J$	-55 ~ +175	$^\circ\text{C}$
Storage temperature range		$T_{STG}$	-55 ~ +175	$^\circ\text{C}$

# Silicon Carbide Power Schottky Diode

**Comchip**  
SMD Diode Specialist

## Electrical Characteristics (at $T_A=25^\circ\text{C}$ unless otherwise noted)

Parameter	Conditions	Symbol	Typ	Max	Unit
Forward voltage	$I_F = 5 \text{ A} , T_J = 25^\circ\text{C}$	$V_F$	1.35	1.7	V
	$I_F = 5 \text{ A} , T_J = 175^\circ\text{C}$		1.55		
Reverse current	$V_R = 650\text{V} , T_J = 25^\circ\text{C}$	$I_R$	10	100	$\mu\text{A}$
	$V_R = 650\text{V} , T_J = 175^\circ\text{C}$		15		
Total capacitive charge	$V_R = 400\text{V} , T_J = 150^\circ\text{C}$ $Q_C = \int_0^{V_R} C(V) dV$	$Q_C$	23		nC
Total capacitance	$V_R = 0\text{V} , T_J = 25^\circ\text{C} , f = 1 \text{ MHz}$	C	430		pF
	$V_R = 200\text{V} , T_J = 25^\circ\text{C} , f = 1 \text{ MHz}$		44		
	$V_R = 400\text{V} , T_J = 25^\circ\text{C} , f = 1 \text{ MHz}$		42.5		

## Typical Characteristics (CDBJFSC5650-G)

Fig.1 - Forward Characteristics

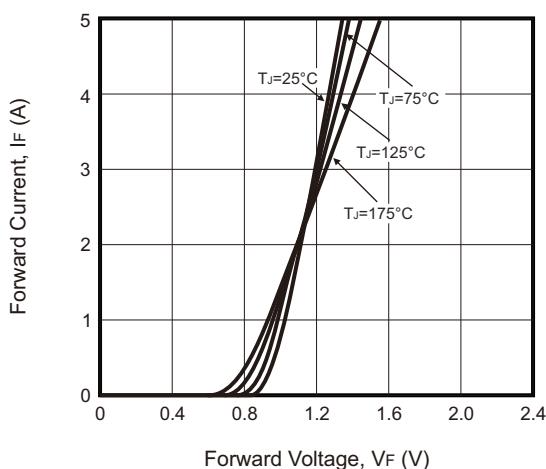


Fig.2 - Reverse Characteristics

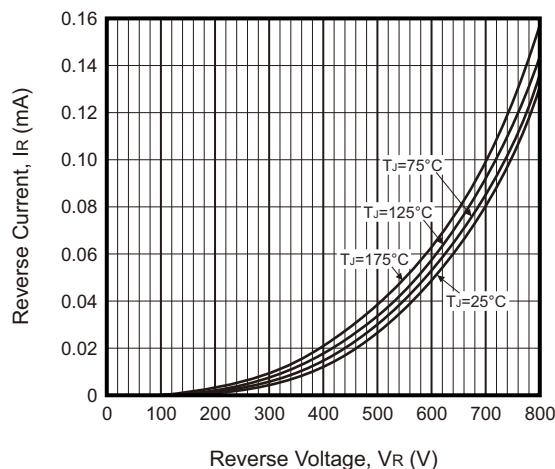


Fig.3 - Current Derating

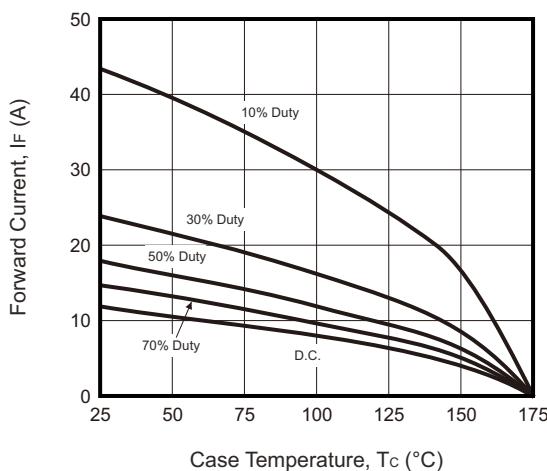
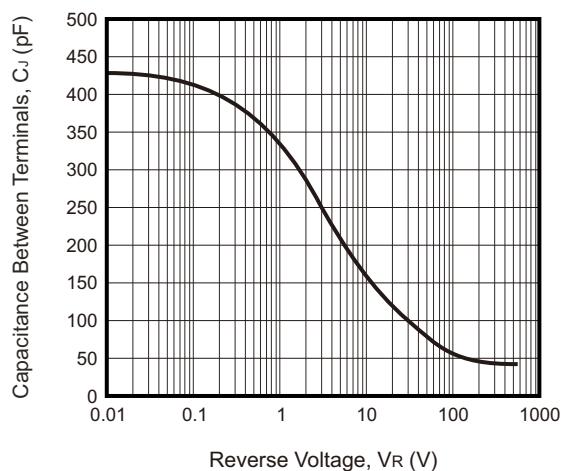
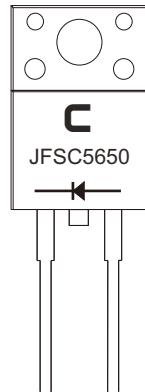


Fig.4 - Capacitance vs. Reverse Voltage

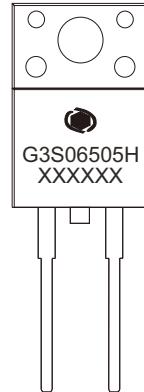


## Marking Code

Part Number	Marking Code	
CDBJFSC5650-G	JFSC5650	G3S06505H



**C** = Comchip Logo



xxxxxx = Control code  
(x from 6 to 11)

## Standard Packaging

Case Type	TUBE PACK	
	TUBE ( pcs )	BOX ( pcs )
TO-220F	50	1,000